

10.0-12.5 GHz 22 dB Gain Low Noise Amplifier

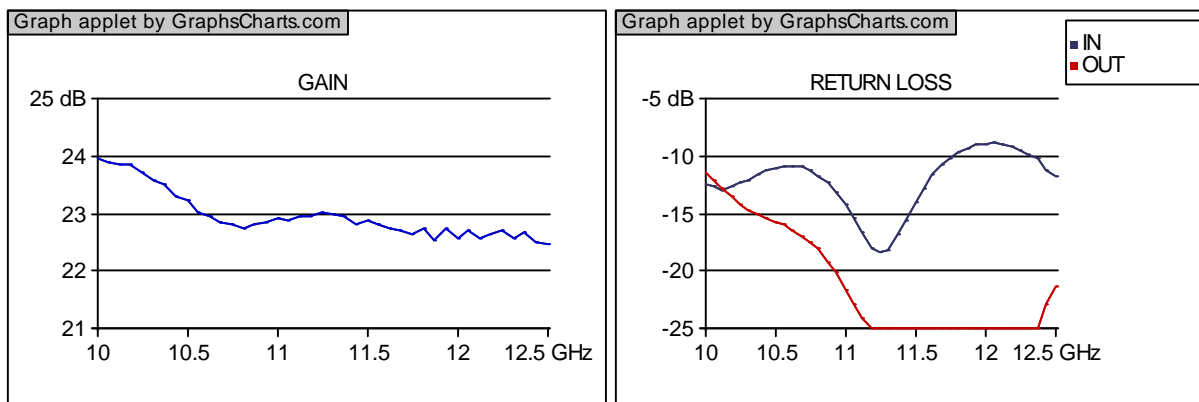
Features:

- Thin Film Hybrid MIC Process
- Field Replaceable SMA Connectors
- Reverse Bias Protection

Electrical Performance

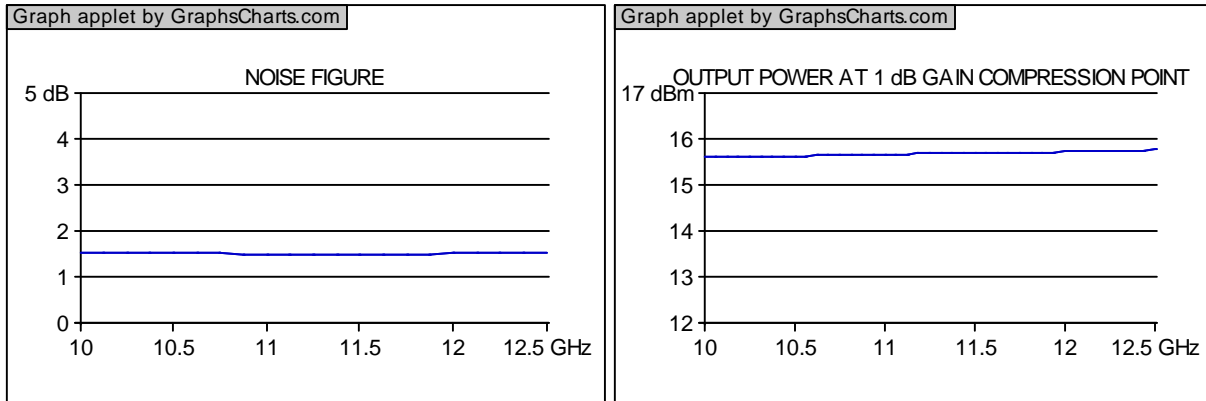
Parameter	Min.	Typ.	Max.	Unit	Note
Frequency	10		12.5	GHz	
Gain	22			dB	
Gain Flatness			1	dB(+/-)	
Noise Figure			1.5	dB	
Power @ 1dB Gain Compression Point	14			dBm	
VSWR Input			2.2		
VSWR Output			1.8		
DC Supply Voltage	12		18	V	
Supplied Current			100	mA	

Typical Test Data

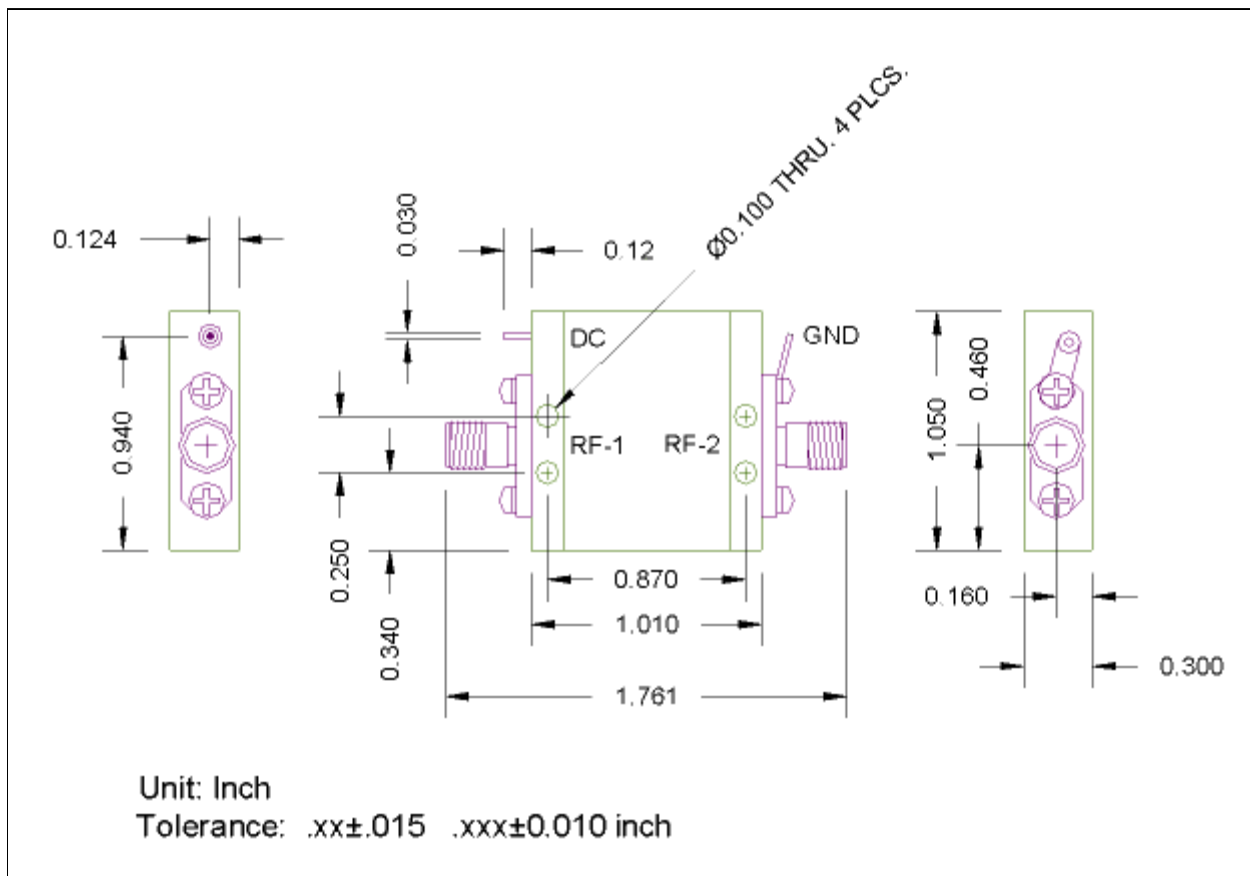


Updated: 12/2/2007

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Outline Drawing



Connector	Type	Pin #	Pin Name	In/Out	Description
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RF-1	SMA-F	1 IN	I	RF SIGNAL INPUT
RF-2	SMA-F	1 OUT	O	RF SIGNAL OUTPUT
DC	EMI Filter	1 +12 V	I	DC INPUT (+12 TO +18 V)
GND	GROUND LUG	1 GND	O	GROUND

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